Topological Phase Transition without Gap Closing

Motohiko Ezawa¹, Yukio Tanaka² and Naoto Nagaosa^{1,3}

Department of Applied Physics, University of Tokyo, Hongo 7-3-1, 113-8656, Japan,

² Department of Applied Physics, Nagoya University, Nagoya 464-8603, Japan, and

³Center for Emergent Matter Science, ASI, RIKEN, Wako 351-0198, Japan

Topological phase transition is accompanied with a change of topological numbers. It has been believed that the gap closing and the breakdown of the adiabaticity at the transition point is necessary in general. However, the gap closing is not always needed to make the topological index ill-defined. In this paper, we show that the states with different topological numbers can be continuously connected *without* gap closing in some cases, where the symmetry of the system changes during the process. Here we propose the generic principles how this is possible (impossible) by demonstrating various examples such as 1D polyacetylene with the charge-density-wave order, 2D silicene with the antiferromagnetic order, 2D silicene or quantum well made of HgTe with superconducting proximity effects and 3D superconductor Cu doped Bi_2Se_3 . It is argued that such an unusual phenomenon can occur when we detour around the gap closing point provided the connection of the topological indices is lost along the detour path.

Topological insulator and superconductor are among the most fascinating concepts in physics found in this decade[1-7]. It is characterized by the topological indices such as the Chern number and the \mathbb{Z}_2 index. When there are two topological distinct phases, a topological phase transition may occur between them. It has been generally accepted that the gap must close at the topological phase transition point since the topological index cannot change its quantized value without gap closing. Note that the topological index is only defined in the gapped system and remains unchanged for any adiabatic process. Alternatively we may think of the edge or surface of the sample in a topological phase. Gapless edge or surface modes appear because the boundary of the sample separates a topological state and the vacuum whose topological indices are zero. The phenomenon is known as the bulk-edge correspondence. We wonder if a topological phase transition cannot occur without gap closing at all.

The topological classes are classified[8] by the eigenvalues of Θ^2 , Ξ^2 and Π^2 , where Θ , Ξ and Π , represent the time-reversal, particle-hole and chiral symmetry operators as shown in Fig.1. There are ten classes, which are separated into two complex and eight real representations. The topological periodic table has been established as in Fig.1(b), which classifies all the possible homotopy groups and topological indices depending on the symmetry and dimensionality of the system. One important fact about this topological periodic table is that the adiabatic connection is possible between the two classes with the difference in dimensions by one[9]. As for the eight real representations, this connection is summarized by the symmetry clock shown in Fig.1(a). Namely, considering the Hamiltonian H(k, r) which depends on both the D-dimensional real space coordinates r and d-dimensional momentum space coordinates k, the mapping connecting the neighboring classes in the symmetry clock is possible by adding r- or k-dependent Hamiltonian[9]. This means that the essential dimensionality is d' = d - D and the adiabatic connection exists next to each other along the *diagonal* direction in the topological periodic table. In addition to this diagonal shift, one can consider the horizontal shift, i.e., dimensionality d' by introducing the defects such as vortex (D = 1), and point defect (D = 2) [10]. There are several works on the *vertical* shift in the periodic table[11–15]. However in these cases, the gap closing is necessary for topological phase transitions.

In this paper, we study the adiabatic connection within the common dimensionality d', and the possible change in the topological indices without closing the gap. We propose two principles. Let the energy spectrum be given by $E_{\rho}(k)$ with a topological phase transition taking place at a critical point $\rho = \rho_{\rm cr}$ of a certain parameter ρ , where the gap closes. Let us assume that we can extend the Hamiltonian to include a new parameter Δ_s so that the energy spectrum is modified as

$$E(k) = \pm \sqrt{E_{\rho}^2(k) + \Delta_s^2}.$$
(1)

The phase transition point is $(\rho_{\rm cr}, 0)$ in the (ρ, Δ_s) phase diagram. We may detour the point $(\rho_{\rm cr}, 0)$ in the phase diagram, along which the gap never closes though a topological phase transition occurs. The second principle is that the topological number should become ill-defined by a symmetry change along the above detour. This invalidates requirements of the gap closing when the topological number changes.

We confirm these generic principles by demonstrating various examples. The first example is a simple one-dimensional model of polyacetylene with reduced symmetry at intermediate states (BDI \rightarrow AI \rightarrow BDI) by way of the charge-density-wave (CDW). We also present a two-dimensional example of silicene with the antiferromagnet (AF) order as another model with symmetry reducing. We then present three models with enhanced symmetry at intermediate state (AII \rightarrow DIII \rightarrow AII) by way of introducing the superconducting (SC) order[8]. They are silicene and quantum well made of HgTe as two-dimensional models, and superconductor Cu doped Bi₂Se₃ as a three-dimensional model.

Polyacetylene with CDW order

We start with presenting a well-known one-dimensional example of polyacetylene with the CDW order from a new



(b)

Symmetry					d' = d - D							
s A	Ζ	Θ^2	Ξ^2	Π^2	0	1	2	3	4	5	6	7
0 A	ł	0	0	0	\mathbb{Z}	0	\mathbb{Z}	0	\mathbb{Z}	0	\mathbb{Z}	0
1 A	III	0	0	1	0	\mathbb{Z}	0	\mathbb{Z}	0	\mathbb{Z}	0	\mathbb{Z}
0 A	Ι	1	0	0	\mathbb{Z}	0	0	0	$2\mathbb{Z}$	0	\mathbb{Z}_2	\mathbb{Z}_2
1 B	DI	1	1	1	\mathbb{Z}_2	\mathbb{Z}	0	0	0	$2\mathbb{Z}$	0	\mathbb{Z}_2
2 I)	0	1	0	\mathbb{Z}_2	\mathbb{Z}_2	\mathbb{Z}	0	0	0	$2\mathbb{Z}$	0
3 D	Ш	$^{-1}$	1	1	0	\mathbb{Z}_2	\mathbb{Z}_2	\mathbb{Z}	0	0	0	$2\mathbb{Z}$
4 A	Π	-1	0	0	$2\mathbb{Z}$	0	\mathbb{Z}_2	\mathbb{Z}_2	\mathbb{Z}	0	0	0
5 C	Π	$^{-1}$	-1	1	0	$2\mathbb{Z}$	0	\mathbb{Z}_2	\mathbb{Z}_2	\mathbb{Z}	0	0
6 (2	0	-1	0	0	0	$2\mathbb{Z}$	0	\mathbb{Z}_2	\mathbb{Z}_2	\mathbb{Z}	0
7 C	ľ	1	-1	1	0	0	0	$2\mathbb{Z}$	0	\mathbb{Z}_2	\mathbb{Z}_2	\mathbb{Z}

FIG. 1: (a) Topological classes and possible class changes. The horizontal axis is $\Theta^2 = 0, \pm 1$, which represents the time-reversal symmetry, while the vertical axis is $\Xi^2 = 0, \pm 1$, which represents the particle-hole symmetry. The eigenvalue 0 means the absence of the symmetry. We present examples of class changes by bold lines that occur without gap closing. AIII resides with the same position as A. (b) Periodic table for the homotopy group of each class. The rows correspond to the different Altland Zirnbauer (AZ) symmetry classes while the columns distinguish different dimensionalities, which depend only on d' = d - D with d-dimensional k space and D-dimensional real space coordinates.

light. Polyacetylene belongs to the class BDI. With including the CDW order, the class change occurs into AI by breaking the time-reversal and particle-hole symmetries simultaneously. We now show that there are two ways of topological phase transitions, one (BDI \rightarrow BDI) with gap closing and the other (BDI \rightarrow AI \rightarrow BDI) without gap closing.

Effective Hamiltonian: Polyacetylene is a bipartite system with one unit cell made of A and B sites. The bipartiteness introduces a pseudospin. We neglect the spin degree of freedom. The tight-binding model is given by [16–19]

$$H_{\text{poly}} = d_x \tau_x + d_y \tau_y \tag{2}$$

in the momentum space, where τ_i is the Pauli matrix acting on the pseudospin $\Psi = \{\psi_A, \psi_B\}$, and

$$d_x = t + \delta + (t - \delta)\cos k, \quad d_y = (t - \delta)\sin k, \quad (3)$$

where k is the momentum $(0 \le k < 2\pi)$, t is the mean transfer integral, δ is the dimerization of the transfer integral. The energy spectrum is given by

$$E_{\rm poly}(k) = \pm 2\sqrt{t^2 \cos^2\frac{k}{2} + \delta^2 \sin^2\frac{k}{2}}.$$
 (4)



FIG. 2: (a) Topological phase diagram in the (δ, m) plane. The horizontal axis is the dimerization δ and the vertical axis is the CDW gap m. The band gap closes at the point denoted by a filled circle. The system is in topological state on the red line along the δ axis. Circles show points where the energy spectrum is calculated for finite chains in (c). (c1)~(c6) Energy spectrum of a finite chain in each point in the phase diagram. The vertical axis is the energy in unit of t and the horizontal axis is the numbering of eigenvalues.

The band gap locates at $k = \pi$, and is given by $2|E_{poly}(\pi)| = 2 |\delta|$. We consider polyacetylene with a finite length. We show the band structure in Figs.2(c1),(c2),(c3). For $\delta < 0$, the system is in the topological phase, as is evidenced by the presence of the gapless edge states in Fig.2 (c1). As $|\delta|$ increases, the gap decreases, and vanishes at $\delta = 0$ as in Fig.2(c2). For $\delta > 0$, the gap opens again but no gapless modes appear as in Fig.2(c3): Hence, it is in the trivial phase. Thus, the topological phase transition occurs with gap closing at $\delta = 0$.

We proceed to introduce CDW to polyacetylene. We assume it to generate the site-energy difference m between the A and B sites. The Hamiltonian is modified as

$$H_{\rm CDW} = H_{\rm poly} + m\tau_z.$$
 (5)

The energy spectrum is modified to be

$$E_{\rm CDW}(k) = \pm \sqrt{[E_{\rm poly}(k)]^2 + m^2},$$
 (6)

which is of the form (1). The gap does not close when $m \neq 0$.

Phase diagram: We explore the topological phase diagram in the (δ, m) plane in Fig.2(a). We show the band gap as a function of the electric field δ and the CDW gap m in Fig.2(b). It is intriguing that the gapless point exists only at one isolated point (0, 0) in the phase diagram. We consider two paths connecting the topological state at $(\delta, 0)$ with $\delta < 0$ and a trivial state at $(\delta, 0)$ with $\delta > 0$ shown in the phase diagram. In Fig.2(c) we show the energy spectrum of finite chain at typical points.



FIG. 3: (a) Bipartite pseudospin in a polyacetylene chain in the momentum space ($0 \le k \le 2\pi$). The pseudospin is confined within the (x, y) plane. The red and blue arrows correspond to the pseudospin configurations (n_x, n_y) for $\delta < 0$ and $\delta > 0$, respectively. They belongs to different homotopy classes with the winding number $N_{\text{wind}} = 1$ and 0. The pseudospin is allowed to have the *z* component in the presence of the CDW order, as indicated by the green arrows. It connects two different classes continuously. (b) The winding number N_{wind} in the (δ, m) space. It changes suddenly at the phase transition point $\delta = 0$ along the δ axis, but smoothly when the point is detoured.

We have already studied the first path along the δ axis. As the second path, we first move along the *m* axis. As changing δ , there is no gap closing even at $\delta = 0$ due to the CDW gap: See Fig.2(c5). When δ exceeds 0 as in Fig.2(c6) we remove the CDW order. The resultant phase is a trivial insulator, as is given by Fig.2(c3) on the δ axis. Along this process the gap never closes. This is an explicit example of a topological phase transition without gap closing.

Topological analysis: We analyze the topological number. For this purpose we define

$$N_{\text{wind}}(m) = \frac{1}{2\pi} \int_{0}^{2\pi} dk \left[n_x \partial_k n_y - n_y \partial_k n_x \right] \\ = \frac{1}{2} - \frac{t\delta + m^2}{2\sqrt{t^2 + m^2}\sqrt{\delta^2 + m^2}}, \tag{7}$$

where $(n_x, n_y, n_z) = (d_x, d_y, m) / \sqrt{d_x^2 + d_y^2 + m^2}$ is the normalized vector, which we illustrate in Fig.3(a).

When m = 0, the pseudospin is confined in the xy plane, and the homotopy class is $\pi_1(S^1) = \mathbb{Z}$. Correspondingly, the quantity (7) takes only two values; $N_{\text{wind}} = 1$ for $\delta < 0$, and $N_{\text{wind}} = 0$ for $\delta > 0$. It is the winding number, as explained in Fig.3(a). Indeed, the system is topological for $\delta < 0$, and trivial for $\delta > 0$.

On the other hand, when the CDW is present $(m \neq 0)$, the pseudospin acquires the z component, and the homotopy class changes to the trivial class $\pi_1(S^2) = 0$. The quantity (7) is no longer the quantized to be an integer. Indeed, we can continuously change $N_{\text{wind}}(m)$ from $N_{\text{wind}}(m) = 1$ to $N_{\text{wind}}(m) = 0$ as we move in the (δ, m) plane: See Fig.3(b).

Silicene with AF order

We next present a two-dimensional example of silicene with the AF order as another model with symmetry reducing.



FIG. 4: (a) Topological phase diagram in the (m_z, m_x) plane. The horizontal and vertical axes are the AF orders m_z and m_x , respectively. (c) We have set $\lambda_{SO} = 0.2t$ for illustration. See also the caption of Fig.2.

Silicene is a honeycomb structure made of silicone atoms. It is a quantum spin-Hall (QSH) insulator[20], and belongs to the class AII. When we introduce the AF order in the z axis, the class changes into A, but it is still a topological insulator. We call it spin-Chern insulator because the time-reversal symmetry is broken. We show that there are two ways of topological phase transitions between the QSH insulator and the trivial insulator with and without gap closing.

Low-energy Dirac theory: We analyze the physics of electrons near the Fermi energy, which is described by Dirac electrons near the K and K' points. We also call them the K_{η} points with the valley index $\eta = \pm$. We introduce the AF order m_z along the z direction. The low-energy Dirac theory reads[13, 21, 22]

$$H_{\eta}^{\text{AFz}} = \hbar v_{\text{F}} \left(\eta k_x \tau_x + k_y \tau_y \right) + \eta \lambda_{\text{SO}} \sigma_z \tau_z - m_z \sigma_z \tau_z, \quad (8)$$

where σ_a and τ_a with a = x, y, z are the Pauli matrices of the spin and the sublattice pseudospin, respectively. The first term arises from the nearest-neighbor hopping, where $v_{\rm F} = \frac{\sqrt{3}}{2\hbar}at = 5.5 \times 10^5 {\rm m/s}$ is the Fermi velocity with the lattice constant a = 3.86Å. The second term is the intrinsic spin-orbit interaction with $\lambda_{\rm SO} = 3.9 {\rm meV}$. The third term represents the AF order. We have neglected the Rashba interaction since its existence does not modify the essential part of the physics. We present the Hamiltonian containing it in Supplementary Information.

The system undergoes a topological phase transition as the AF order m_z changes[13]. The energy spectrum is given by

$$E^{\text{AFz}}(k) = \pm \sqrt{(\hbar v_{\text{F}})^2 k^2 + (\eta \lambda_{\text{SO}} - m_z)^2}.$$
 (9)

The system is a topological insulator for $|m_z| < 2\lambda_{SO}$ with

the gap $2|\lambda_{SO} - m_z|$, as is evidenced by the emergence of gapless edge modes based on the bulk-edge correspondence: See Fig.4(c1). As ηm_z changes at the K_η point, the gap decreases and closes at the critical point $m_z = \eta \lambda_{SO}$, as in Fig.4(c2). Then, the gap opens again, but there appear no longer gapless edge modes as in Fig.4(c3), indicating that the system is in the trivial phase. The Chern and spin-Chern numbers are calculated to be

$$(\mathcal{C}, \mathcal{C}_{\rm spin}) = \begin{cases} (0, 1) \text{ for } |m_z| < \lambda_{\rm SO} \\ (0, 0) \text{ for } |m_z| > \lambda_{\rm SO} \end{cases} .$$
(10)

This is a typical example of a topological phase transition with gap closing.

Let us now introduce the AF order additionally in the x and y directions. The low-energy Dirac theory is given by

$$H_{\eta}^{\rm AF} = H_{\eta}^{\rm AFz} - (m_x \sigma_x + m_y \sigma_y) \tau_z. \tag{11}$$

The energy spectrum is given by

$$E^{\rm AF}(k) = \pm \sqrt{[E^{\rm AFz}(k)]^2 + m_x^2 + m_y^2}, \qquad (12)$$

which is of the form (1). The band gap locates at k = 0, and is given by $2|E_{\rm si}(0)| = 2\sqrt{(\eta\lambda_{\rm SO} - m_z)^2 + m_x^2 + m_y^2}$. It closes only at $(m_x, m_y, m_z) = (0, 0, \eta\lambda_{\rm SO})$.

Phase diagram: We explore the phase diagram in the (m_z, m_x) plane with $m_y = 0$ in Fig.4(a). We show the band gap as a function of the AF orders m_z and m_x in Fig.4(b). The gapless points exist only at two isolated points $(\eta\lambda_{SO}, 0)$ in the phase diagram. We consider two paths connecting the QSH state at the origin and a trivial state at $(m_z, 0)$ with $m_z > \lambda_{SO}$ shown in the phase diagram. In Fig.4(c) we show the band structure of silicene with edges at typical points. Along the detour the gap never closes. Hence we have shown that there are two ways of topological phase transitions with and without gap closing.

Topological analysis: Silicene is a topological insulator characterized by the Chern number and the \mathbb{Z}_2 index. It is to be noted that the *z* axis has been chosen by the intrinsic SO interaction in the Hamiltonian (8). As far as the AF order is along the *z* axis, there exists a rotational symmetry around the *z* axis. The system is the sum of two decoupled systems of $s_z = 1/2$ and -1/2, and their respective Chern numbers are the topological indices in this case. Equivalently, one can define the sum (Chern number) and the half of the difference (spin-Chern number) of these two Chern numbers. Note that the \mathbb{Z}_2 index is well defined when the time-reversal symmetry is present while the spin-Chern number. They are equal mod 2 when both of them are well defined[23].

When $m_x = m_y = 0$, the spin-Chern number C is well-defined. The topological phase is indexed by $C_{spin} = 1$. However, when we introduce m_x , the AF direction cants, and the spin-Chern number becomes ill-defined. The system becomes a trivial insulator for $m_x \neq 0$ or $m_y \neq 0$. After we make a detour around the critical point, we decreases m_x until $m_x = 0$, where the spin-Chern number becomes well-defined again. However, the system is in the trivial phase with $C_{\rm spin} = 0$ when $m_z > \lambda_{\rm SO}$.

Helical edge states with AF order: It is quite interesting that the QSH insulator becomes a trivial insulator as soon as m_x is introduced. (We assume $m_z = 0$ for simplicity.) We are able to construct an effective low energy theory to explain how such a transition occurs. The helical edges are described by the 4×4 -matrix Hamiltonian given by

$$H_{\text{edge}} = \begin{pmatrix} (\lambda_{\text{SO}}/t)\hbar v_{\text{F}}k\sigma_z & m_x\sigma_x \\ m_x\sigma_x & -(\lambda_{\text{SO}}/t)\hbar v_{\text{F}}k\sigma_z \end{pmatrix}.$$
 (13)

It is diagonalized as

$$E_{\text{BdG}}(k) = \sqrt{\left(\frac{\lambda_{\text{SO}}}{t}\hbar v_{\text{F}}k\right)^2 + m_x^2}.$$
 (14)

The Hamiltonian describes two edge modes crossing at k = 0for $m_x = 0$. As soon as $m_x \neq 0$, the level crossing turns into the level anticrossing, with open gap. The gap monotonously increases as $|m_x|$ increases. The system is topological for $m_x = 0$ and is trivial for $m_x \neq 0$.

Silicene with SC order

We then present three models with symmetry increasing transitions (AII \rightarrow DIII) by way of superconducting proximity effect[24–29]. The system is in the class AII without the SC order, and the gap closing occurs at the topological phase transition point separating the two phases with $\mathbb{Z}_2 = 1$ and 0. However, we are able to make a topological phase transition (AII \rightarrow DIII \rightarrow AII) to occur without gap closing by switching on and off the SC order.

The first model is silicene with the SC order, which might be experimentally achieved by silicene synthesized on the Ir substrate, which has recently been found[30]. Its prominent feature is that Ir is superconducting at 0.1K. This opens a natural way to fabricate superconducting proximity effects on to silicene by cooling down the system made of silicene together with the Ir substrate.

Low-energy Dirac theory: We analyze silicene by applying external electric field perpendicular to the sheet. The effective Dirac Hamiltonian in the momentum space reads[21, 22, 31]

$$H_{\eta} = \hbar v_{\rm F} \left(\eta k_x \tau_x + k_y \tau_y \right) + \lambda_{\rm SO} \sigma_z \eta \tau_z - V \tau_z.$$
(15)

The third term is the staggered potential term V induced by the electric field.

The system exhibits a topological phase transition from a QSH insulator to a trivial insulator as |V| increases[31]. The energy spectrum is given by

$$E_{\rm si}(k) = \pm \sqrt{(\hbar v_{\rm F})^2 k^2 + (\eta s_z \lambda_{\rm SO} - V)^2},$$
 (16)

FIG. 6: (a) Illustration of silicene in torus geometry with the SC order on one-half of the system. The upper half region is in the trivial phase with the SC order included, while the lower half is in the QSH phase. Band structures of silicene in torus geometry (b) without the SC order and (c) with the the SC order on one-half of the system. The vertical axis is the energy in unit of t, while the horizontal axis is the momentum k.

k

2π 0

the sample below the critical temperature of superconductivity. As soon as the critical temperature is passed, a topological class change occurs by adding the particle-hole symmetry associated with the Cooper-pair condensation. The SC gap mixes the helical edge modes, resulting in the disappearance of gapless edge modes, and the system becomes trivial [Fig.5(c4)]. The mechanism how the helical edge modes disappear is precisely the same as we demonstrated before: See Eq.(14). After the detour we warm up the sample. The superconductivity disappears. The resultant phase is a trivial insulator, as is given by Fig.5(c3) on the V axis. Along this process the gap never closes.

Let us study this class change more in detail to confirm that it does not involve the gap closing. For this purpose we analyze a system where SC is attached on one-half of the system. It is important to demonstrate whether there emerge edge states between the boundary of the two regions [24, 32]. The region without SC is in the QSH phase, while the superconducting region is in the trivial phase. We may alternatively calculate the band structure of silicene in torus geometry with the SC order introduced to one-half side of a cylinder [Fig.6(a)]. Note that there are no edge states in silicene in torus geometry even in the QSH phase. The band structure is well known[33] and given in Fig.6(b). Once the superconducting gap is introduced partially as in Fig.6(a), two boundaries appear between the SC and normal regions. We naively expect the emergence of gapless edge modes along each boundary due to the bulk-edge correspondence, as is the case[33] between the QSH phase and the trivial phase. Nevertheless, we find no gapless edge states to appear as in Fig.6(c). This reflects the fact that the topological phase changes between $\Delta_s = 0$ and $\Delta_s \neq 0$ undergoes without gap closing.

Topological analysis: We next search for the reason why a topological phase transition can occur without gap closing as soon as the superconductor gap Δ_s is introduced. For this purpose we investigate the topological charges of the system. With the superconducting proximity effects, silicene belongs to the class DIII. Thus the topological class change occurs from AII to DIII as soon as the superconductor gap Δ_s is introduced, i.e., by adding the particle-hole and chiral symmetries. Both classes AII and DIII are characterized by the \mathbb{Z}_2 indices. However they are different objects. Consequently,

FIG. 5: (a) Topological phase diagram in the (V, Δ_s) plane. The horizontal axis is the electric field V and the vertical axis is the superconducting gap Δ_s . (c) We have set $\lambda_{SO} = 0.2t$ for illustration. See also the caption of Fig.2.

-1.0

The band gap locates at k = 0, and is given by $2|E_{si}(0)| = 2|\eta s_z \lambda_{SO} - V|$. It closes at $V = \pm \lambda_{SO}$. The QSH state has gapless edge states as in Fig.5 (c1). At $V = \lambda_{SO}$, the gap closes as in Fig.5 (c2), and it opens for $V > \lambda_{SO}$ as in Fig.5 (c3). The Chern and spin-Chern numbers are calculated to be

$$(\mathcal{C}, \mathcal{C}_{\text{spin}}) = \begin{cases} (0, 1) \text{ for } |V| < |\lambda_{\text{SO}}| \\ (0, 0) \text{ for } |V| > |\lambda_{\text{SO}}| \end{cases},$$
(17)

This is a typical example of a topological phase transition with gap closing.

We assume that Cooper pairs are formed by mixing electrons at the K and K' points and condense in silicene by attaching the s-wave SC. We present the BCS Hamiltonian and the associated BdG Hamiltonian in Supplementary Information.

It is straightforward to diagonalize the BdG Hamiltonian,

$$E_{\rm BdG}(k) = \pm \sqrt{[E_{\rm si}(k)]^2 + \Delta_s^2},$$
 (18)

which is of the form (1). The band gap locates at k = 0, and it closes at $(\pm \lambda_{SO}, 0)$ in the (V, Δ_s) plane.

Phase diagram: We explore the phase diagram in the (V, Δ_s) plane in Fig.5(a). We show the band gap as a function of the electric field V and the SC gap Δ_s in Fig.5(b). The gapless points exist only at two isolated points $(\pm \lambda_{SO}, 0)$ in the phase diagram. We consider two paths connecting the QSH state at the origin and a trivial state at (V, 0) with $V > \lambda_{SO}$ shown in the phase diagram. In Fig.5(c) we show the band structure of silicene with edges at typical points.

As to the second path, we first move along the Δ_s axis from the origin in the phase diagram. Namely, we cool down k

2π

(c) with parital SC odering



although we have given the phase diagram in Fig.5(a), each domain is indexed by different topological indices.

Since the spin s_z is a good quantum number along the E axis in the phase diagram, the \mathbb{Z}_2 index is essentially the spin-Chern number for $\Delta_s = 0$. The latter counts the numbers of up-spin electrons and down-spin electrons separately. When the SC order is introduced, the ground state is a condensed phase of Cooper pairs each of which is a pair of up-spin and down spin electrons. Consequently, the spin Chern number becomes ill-defined for $\Delta_s \neq 0$, and the gap closing is not required between the QSH state at $\Delta_s = 0$ and a trivial state at $\Delta_s \neq 0$.

A comment is in order. Here we have assumed the singlet SC order. When we assume the triplet SC order, the energy spectrum is shown to be of the form

$$E_{\text{BdG}}(k) = \pm \sqrt{\left(\hbar v_{\text{F}}\right)^2 k^2 + \left(\sqrt{\lambda_{\text{SO}}^2 + \Delta_t^2 k^2} - |V|\right)^2}.$$
 (19)

The triplet SC parameter Δ_t does not contribute to the gap at k = 0. The gap closing occurs although this is a topological class change from AII to DIII together with the Bose-Einstein condensation. This is not surprising since the spin-Chern number is well-defined for $\Delta_t \neq 0$ because the members of a Cooper pair are either up-spin or down-spin electrons.

Quantum well made of HgTe and CdTe

We present another two-dimensional example, which is the Bernevig-Hughes-Zhang (BHZ) model of the QSH system. The BHZ model describes the electronic structure of the subband of a quantum well made of HgTe and CdTe[34], which is experimentally verified[35]. A topological phase transition can be induced by changing the thickness of the quantum well.

The Hilbert space is spanned by the four states which are eigenstates of the operator m_J , $|\pm 1/2\rangle$ and $|\pm 3/2\rangle$. We present the BHZ Hamiltonian in Supplementary Information. The energy spectrum is determined as

$$E_{\text{BHZ}}(k) = C - Dk^2 \pm \sqrt{Ak^2 + (M - Bk^2)^2},$$
 (20)

where A, B, C, D are sample-dependent parameters, and M is the Dirac mass. The topological phase transition is known to occur at M = 0.

To explain it let us slightly simplify the model by choosing C = 0. Then, the energy spectrum is simplified as

$$E_{\rm BHZ}(k) = -Dk^2 \pm \sqrt{Ak^2 + (M - Bk^2)^2}.$$
 (21)

The band gap locates at k = 0, and is given by $2|E_{BHZ}(0)| = 2|M|$. We show the band structure of silicene with edges in Figs.7(c1),(c2),(c3). For M/B < 0, the system is in the topological phase, as is evidenced by the presence of the gapless edge modes in Fig.7(c1). As |M| decreases, the gap decreases, and closes at M = 0 as in Fig.7(c2). For



FIG. 7: (a) Topological phase diagram in the (M, Δ_s) plane. The horizontal axis is the Dirac mass M and the vertical axis is the superconducting gap Δ_s . The vertical axis is the energy in unit of B. We have set A = B = 1, C = D = 0. See also the caption of Fig.2.

M/B > 0, the gap opens again but no gapless modes appear as in Fig.7(c3): Hence, it is in the trivial phase. Thus, the topological phase transition occurs with gap closing.

We proceed to assume that the singlet Cooper pairs are formed due to the SC proximity effects with the SC gap Δ_s . The first pairing is between $|1/2\rangle$ and $|-1/2\rangle$. The second pairing is between $|3/2\rangle$ and $|-3/2\rangle$. In general these two gaps are different, but we assume them to be equal for simplicity. The BdG Hamiltonian is derived and given in Supplementary Information. It is diagonalized as

$$E_{\text{BdG}}(k) = \pm \sqrt{(E_{\text{BHZ}}(k))^2 + \Delta_s^2},$$
 (22)

where each level is two-fold degenerate. The gap does not close when $\Delta_s \neq 0$.

We show the topological phase diagram in the (M, Δ_s) plane, the band gap and the band structure of silicene with edges with straight edge in Fig.7. Employing the same discussion as in the case of silicene, we find that it is possible to make a topological phase transition without gap closing.

Cu doped Bi₂Se₃

Finally we present a three-dimensional example. Bi_2Se_3 is a three-dimensional topological insulator[36]. On the other hand, Cu doped $Bi_2Se_3[37-39]$ becomes superconducting at low temperature[37-40]. The topological class change occurs from AII to DIII.

The Hamiltonian is given by [41, 42]

$$H_{\text{BiSe}} = m(k)\tau_x + v_z k_z \tau_y + v \tau_z \left(k_x \sigma_y - k_y \sigma_x\right) - \mu, \quad (23)$$

with the chemical potential μ , and

$$m(k) = m_0 + m_1 k_z^2 + m_2 \left(k_x^2 + k_y^2\right), \qquad (24)$$

where σ_a and τ_a with a = x, y, z are the Pauli matrices of the spin and the orbital pseudospin, respectively: (v, v, v_z) is the Fermi velocity, and m_i are sample parameters. The system is topological when $m_0m_1 < 0$ and trivial when $m_0m_1 > 0$. The energy spectrum is given by

$$E_{\text{BiSe}}(k) = -\mu \pm \sqrt{v^2(k_x^2 + k_y^2) + v_z^2 k_z^2 + m(k)^2}.$$
 (25)

The band gap locates at the Γ point with $k_x = k_y = k_z = 0$, where $E_{\text{BiSe}}(0) = \pm |m_0|$. The band gap is $2|m_0|$.

We cool the system below the SC transition point. There are four possible superconducting pairing[39]. The simplest one is the intra-orbital spin-singlet pairing, which results in trivial superconductor. The other three pairings lead to topological superconductor. We concentrate on the intra-orbital spin-singlet pairing since only this pairing enables the topological class change without gap closing. The BdG Hamiltonian is derived and given in Supplementary Information. It is diagonalized as

$$E_{\text{BdG}}(k) = \pm \sqrt{[E_{\text{BiSe}}(k)]^2 + \Delta_s^2},$$
 (26)

where each level is two-fold degenerate. The gap does not close when $\Delta_s \neq 0$. In the same way, the topological class change occurs without gap closing in the three-dimensional space.

Topological superconductor

We have so far studied a model Hamiltonian where the initial and final states are normal state without SC order. Here, we consider a situation where initial and final states are SC states. We consider a model Hamiltonian of two-dimensional spin-triplet p_x -wave superconductor with opposite spin pairing $S_z = 0$ or spin-singlet d_{xy} -wave one. Although the initial Hamiltonian is 4×4 matrix in the electron-hole and spin spaces, it can be block diagonalized by 2×2 matrix in the absence of magnetic scattering and spin-orbit coupling. In order to consider the edge state for flat surface parallel to the y direction, we fix momentum k_y . Then, the original twodimensional Hamiltonian is reduced to be one-dimensional one. The resulting Hamiltonian can be written as

$$H = \varepsilon \tau_z + \Delta(k_x) \sin k_x \tau_x \tag{27}$$

with $\Delta(k_x) = \Delta_0$ for p_x -wave pairing and $\Delta(k_x) = \Delta_0 \sin k_x$ for d_{xy} -wave one, respectively.

The energy spectrum of this Hamiltonian is

$$E = \pm \sqrt{\varepsilon^2 + \Delta^2(k_x) \sin^2 k_x}$$
(28)

with $\varepsilon = -t \cos k_x - \mu$ and t > 0 with $\mu = \mu_0 + t \cos k_y$. For $|\mu| < t$, the superconducting state becomes topological with

the zero-energy surface Andreev bound state[43, 44]. On the other hand, for $|\mu| > t$, it becomes trivial without zero energy ABS. For $|\mu| = t$, the gap closing occurs at $k_x = 0$ or $k_x = \pm \pi$. It has been clarified that the zero energy surface Andreev bound state is protected by the bulk topological number[45].

Now, let us introduce an additional term $\Delta_1 \tau_y$. Then, the time reversal symmetry is broken and the resulting Hamiltonian becomes

$$H = \varepsilon \tau_z + \Delta(k_x) \sin k_x \tau_x + \Delta_1 \tau_y.$$
⁽²⁹⁾

The energy spectrum is obtained as

$$E = \pm \sqrt{\varepsilon^2 + \Delta^2(k_x) \sin^2 k_x + \Delta_1^2}.$$
 (30)

There is no gap closing for all k_x and μ .

We first start from the topological phase with $\Delta_1 = 0$ with $|\mu| < t$. Next, we switch on Δ_1 . Then, the system becomes a fully gapped one with time reversal symmetry breaking. We can change μ from $|\mu| < t$ to $|\mu| > t$. During this change, there is no gap closing. After we switch off Δ_1 , we reach the topological trivial phase of the original Hamiltonian. One of the example relevant to the intermediate state is d_{xy} -wave superconductor with *s*-wave pairing, where the relative phase between these two states is $\pi/2$. The $(d_{xy}+is)$ -wave pairing was focused on as the possible surface state of d_{xy} -wave pairing in the context of Cuprate[46].

Conclusions

A topological phase transition requires in general the gap closing and the breakdown of the adiabaticity at the transition point. This is not necessarily the case provided a topological class or symmetry change occurs such that the original set of topological indices become ill-defined. There exists two possibilities of symmetry change. Both the cases with reduced symmetry and enhanced symmetry have been considered. When the symmetry is reduced, the target space of the Hamiltonian becomes wider, which enables us to connect two distinct spaces adiabatically. As such an example we have considered a one-dimensional example of polyacetylene by way of the CDW, which induces the class change $BDI \rightarrow AI$. Here, the homotopy class changes from $\pi_1(S^1) = \mathbb{Z}$ to $\pi_1(S^2) = 0$, and the winding number becomes ill-defined. Consequently, we are able to make a topological phase transition (BDI \rightarrow AI \rightarrow BDI) to occur without gap closing by switching on and off the CDW. We have also analyzed silicene with the AF order as another example with symmetry reducing. It is interesting that a topological phase transition without gap closing takes place within the same class A. However, there is a symmetry change whether the spin s_z is a good quantum number and not.

When the symmetry is enhanced, the above reasoning no longer follows. As such examples we have considered symmetry increasing transitions (AII \rightarrow DIII) by way of introducing the SC order. Although both the classes AII and DIII are

characterized by the \mathbb{Z}_2 index, their physical meaning is different. The \mathbb{Z}_2 index is essentially the spin-Chern number in the class AII system, which becomes ill-defined as soon as the system moves into the SC phase (DIII) due to the SC order. We have explicitly shown that a topological phase transition (AII \rightarrow DIII \rightarrow AII) may occur without gap closing by switching on and off the SC order.

To conclude, we mention the implications of the adiabatic connection between the different sectors of topological number. Up to now only the single-particle Hamiltonian has been considered, but in reality the electron-electron interaction is effective, and the gaps are often induced by the order parameters. Therefore, the character of the quantum critical phenomenon depends strongly on whether the continuous change of the topological number is possible or not. Namely, when we write down the effective action for the quantum phase transition, there are multiple order parameters relevant to the gapless point when the continuous detour is possible to change the topological number. When the multiple topological phase transitions merges at one point, even more interesting quantum critical phenomenon is expected. The global view of the phase diagram taking into account all the possible classes will be an important direction to study the topological quantum transition.

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